

**SPTECH Silicon PNP Power Transistor**

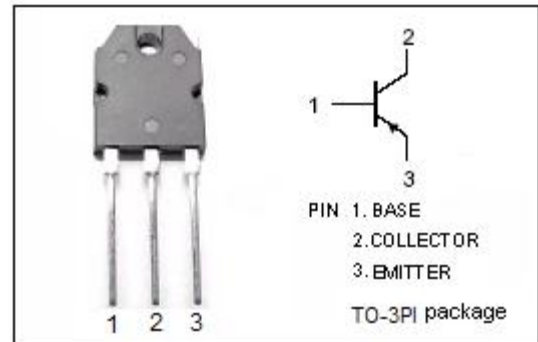
**2SA1941**

**DESCRIPTION**

- Low Collector Saturation Voltage-  
:  $V_{CE(sat)} = -2.0V(\text{Min}) @ I_C = -7A$
- Good Linearity of  $h_{FE}$
- Complement to Type 2SC5198

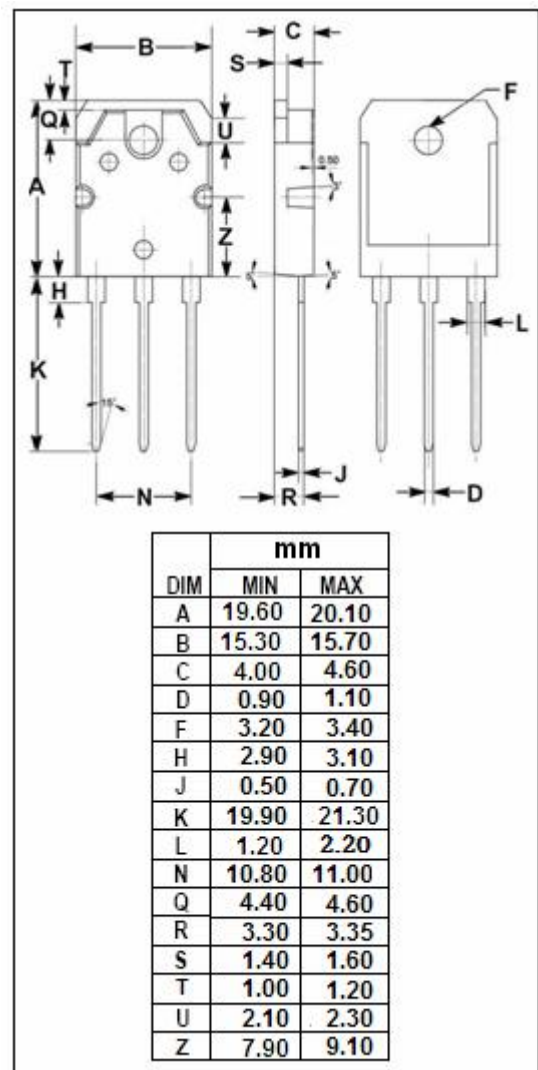
**APPLICATIONS**

- Power amplifier applications
- Recommend for 70W high fidelity audio frequency amplifier output stage applications



**ABSOLUTE MAXIMUM RATINGS( $T_a=25^\circ\text{C}$ )**

SYMBOL	PARAMETER	VALUE	UNIT
$V_{CBO}$	Collector-Base Voltage	-140	V
$V_{CEO}$	Collector-Emitter Voltage	-140	V
$V_{EBO}$	Emitter-Base Voltage	-5	V
$I_C$	Collector Current-Continuous	-10	A
$I_B$	Base Current-Continuous	-1	A
$P_C$	Collector Power Dissipation @ $T_c=25^\circ\text{C}$	100	W
$T_J$	Junction Temperature	150	$^\circ\text{C}$
$T_{stg}$	Storage Temperature Range	-55~150	$^\circ\text{C}$



**ELECTRICAL CHARACTERISTICS**

$T_C=25^{\circ}\text{C}$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	$I_C = -50\text{mA}; I_B = 0$	-140			V
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = -7.0\text{A}; I_B = -0.7\text{A}$			-2.0	V
$V_{BE(on)}$	Base-Emitter On Voltage	$I_C = -5\text{A}; V_{CE} = -5\text{V}$			-1.5	V
$I_{CBO}$	Collector Cutoff Current	$V_{CB} = -140\text{V}; I_E = 0$			-5	$\mu\text{A}$
$I_{EBO}$	Emitter Cutoff Current	$V_{EB} = -5\text{V}; I_C = 0$			-5	$\mu\text{A}$
$h_{FE-1}$	DC Current Gain	$I_C = -1\text{A}; V_{CE} = -5\text{V}$	55		160	
$h_{FE-2}$	DC Current Gain	$I_C = -5\text{A}; V_{CE} = -5\text{V}$	35			
$C_{OB}$	Output Capacitance	$I_E = 0; V_{CB} = -10\text{V}; f_{test} = 1.0\text{MHz}$		320		pF
$f_T$	Current-Gain—Bandwidth Product	$I_C = -1\text{A}; V_{CE} = -5\text{V}$		30		MHz

◆  **$h_{FE-1}$  Classifications**

R	O
55-110	80-160